

March 2013

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FDPF8N60ZUT N-Channel UniFETTM Ultra FRFETTM MOSFET

FDPF8N60ZUT N-Channel UniFETTM Ultra FRFETTM MOSFET 600 V, 6.5 A, 1.35 Ω

Features

- + R_{DS(on)} = 1.15 $\Omega\,$ (Typ.) @ V_{GS} = 10 V, I_D = 3.25 A
- Low Gate Charge (Typ. 20 nC)
- Low C_{rss} (Typ. 10 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- RoHS Compliant

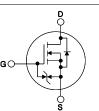
Applications

- LCD/LED TV
- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor[®]'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. UniFET Ultra FRFETTM MOSFET has much superior body diode reverse recovery performance. Its t_{rr} is less than 50nsec and the reverse dv/dt immunity is 20V/nsec while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore UniFET Ultra FRFET MOSFET can remove additional component and improve system reliability in certain applications that require performance improvement of the MOSFET's body diode. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





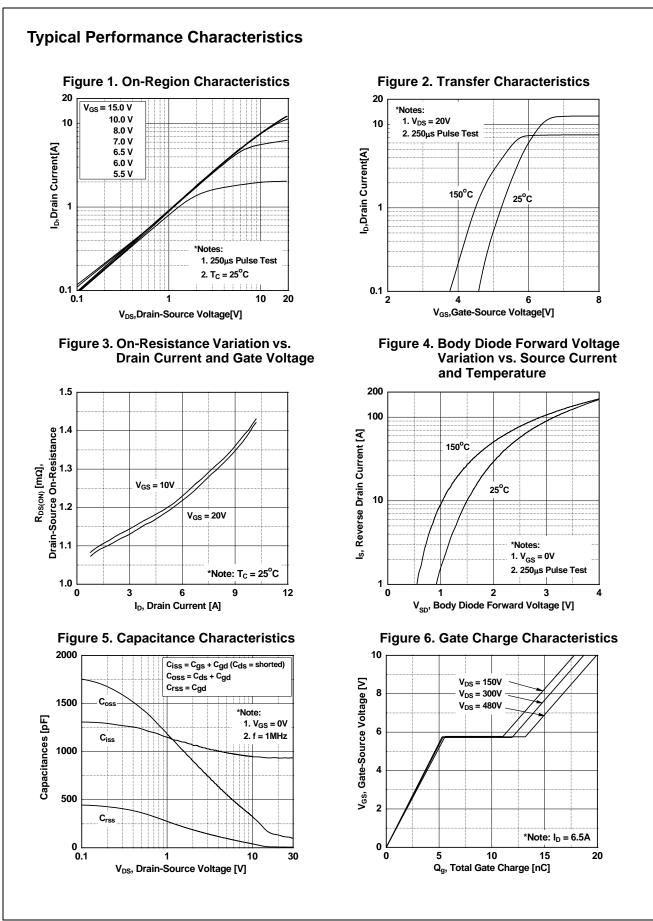
MOSFET Maximum Ratings T_C = 25°C unless otherwise noted*

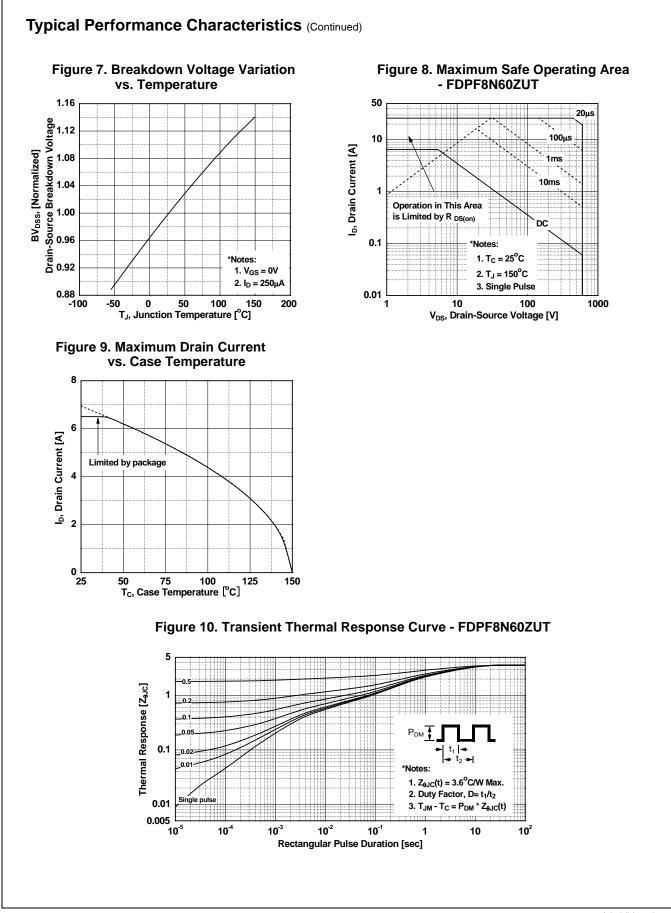
Symbol			FDPF8N60ZUT	Unit	
V _{DSS}	Drain to Source Voltage	Source Voltage			V
V _{GSS}	Gate to Source Voltage			±30	V
I _D	Desire Course et	- Continuous ($T_C = 25^{\circ}C$)		6.5*	
	Drain Current	- Continuous ($T_C = 100^{\circ}C$)		3.9*	Α
I _{DM}	Drain Current	- Pulsed (Note 1)		26*	А
E _{AS}	Single Pulsed Avalanche En	ergy	(Note 2)	420	mJ
I _{AR}	Avalanche Current		(Note 1)	6.5	А
E _{AR}	Repetitive Avalanche Energy	/	(Note 1)	13.5	mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	20	V/ns
P _D	Deven Directory	$(T_{\rm C} = 25^{\rm o}{\rm C})$		34.5	W
	Power Dissipation	- Derate above 25°C		0.28	W/ºC
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds			300	°C
	limited by maximum junction tempe Characteristics	erature			
Symbol		Parameter		FDPF8N60ZUT	Unit
,	Thermal Desistance, Junction to Good, May			2.0	

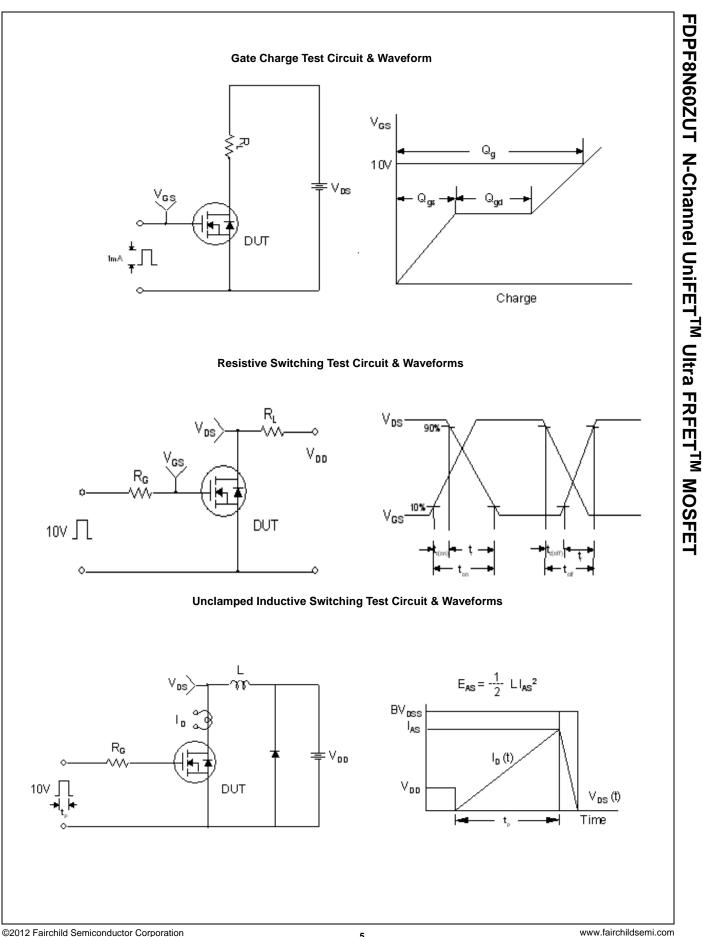
Symbol	Parameter	FDPF8N60ZUT	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	3.6	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	0/11

		Packag	е	Reel Size	Тар	e Width		Quantit	у	
		TO-220	-			-		50		
Electrica	I Chai	racteristics T _c =	= 25ºC unless	otherwi	se noted					
Symbol		Parameter		Test Conditions		Min.	Тур.	Max.	Unit	
Off Charac	teristic	s								
BV _{DSS}	Drain te	o Source Breakdown V	/oltage	I _D = 250μA, V _{GS} = 0V, T _J = 25°C			600	-	-	V
ΔBV_{DSS}	Breakd	Iown Voltage Temperat	0	$I_D = 250 \mu A$, Referenced to $25^{\circ}C$		-	0.7	-	V/°C	
ΔT_{J}	Coefficient			V _{DS} = 600V, V _{GS} = 0V			_	_	25	
I _{DSS}	Zero Gate Voltage Drain Current		ent	$V_{DS} = 480V, T_{C} = 125^{\circ}C$			-	-	250	μA
I _{GSS}	Gate to	to Body Leakage Current			$\pm 30V, V_{DS} = 0V$		-	-	±10	μA
On Charac				1 00	. 20				1	
V _{GS(th)}	Gate Threshold Voltage			V _{GS} = V _{DS} , I _D = 250μA			3.0	-	5.0	V
R _{DS(on)}		Static Drain to Source On Resistance			$V_{GS} = 10V, I_D = 3.25A$			1.15	1.35	Ω
9FS	Forwar	rward Transconductance			$V_{DS} = 40V, I_D = 3.25A$			7	-	S
C _{iss} C _{oss} C _{rss}	Output	Capacitance Capacitance Se Transfer Capacitanc			− V _{DS} = 25V, V _{GS} = 0V − f = 1MHz		-	110 10	150 15	pF pF pF
			e			-	20	26	p⊢ nC	
Q _g Q _{gs}		Total Gate Charge at 10V Gate to Source Gate Charge Gate to Drain "Miller" Charge		$V_{DS} = 480V, I_D = 6.5A$ $V_{GS} = 10V$ (Note 4)		-	5	-	nC	
							8	_	nC	
Q _{gd}						-	0	-	nc	
Switching				1						
t _{d(on)}	Turn-On Delay Time		V _{DD} = 300V, I _D = 6.5A		-	20	50	ns		
t _r		n Rise Time		$R_{G} = 25\Omega, V_{GS} = 10V$		F	-	30	70 120	ns
t _{d(off)}		ff Delay Time				-	55 35	80	ns ns	
t _f ESR	Turn-Off Fall Time Equivalent Series Resistance			(Note 4) f = 1MHz			- 0.5	5	11	Ω
				- IV			0.0	5		22
	1	de Characteristic		Forward	ard Current		-		6.5	A
I _S I _{SM}	Maximum Continuous Drain to Source Diode Maximum Pulsed Drain to Source Diode For					_	-	26	A	
V _{SD}	Drain to Source Diode Forward Voltage		$V_{GS} = 0V, I_{SD} = 6.5A$			-	-	1.6	V	
t _{rr}		e Recovery Time			: 0V, I _{SD} = 6.5A		-	40	-	ns
		e Recovery Charge		$dI_{F}/dt = 100A/\mu s$			-		-	

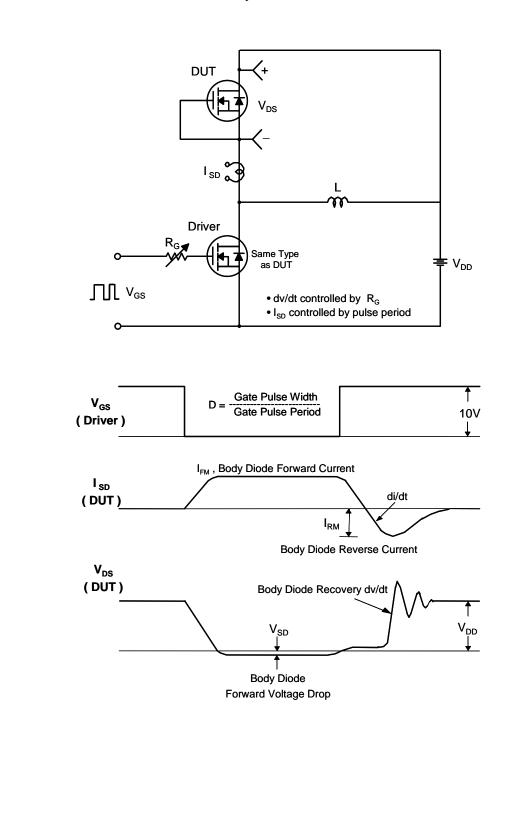
 $\label{eq:Notes: 1} \begin{array}{l} \text{Notes:} \\ 1: \ \text{Repetitive Rating: Pulse width limited by maximum junction temperature} \\ 2: \ L = 20mH, \ I_{AS} = 6.5A, \ V_{DD} = 50V, \ R_G = 25\Omega, \ \text{Starting } T_J = 25^{\circ}\text{C} \\ 3: \ I_{SD} \leq 6.5A, \ \text{di/dt} \leq 200A/\mu S, \ V_{DD} \leq BV_{DSS}, \ \text{Starting } T_J = 25^{\circ}\text{C} \\ 4: \ \text{Essentially Independent of Operating Temperature Typical Characteristics} \end{array}$

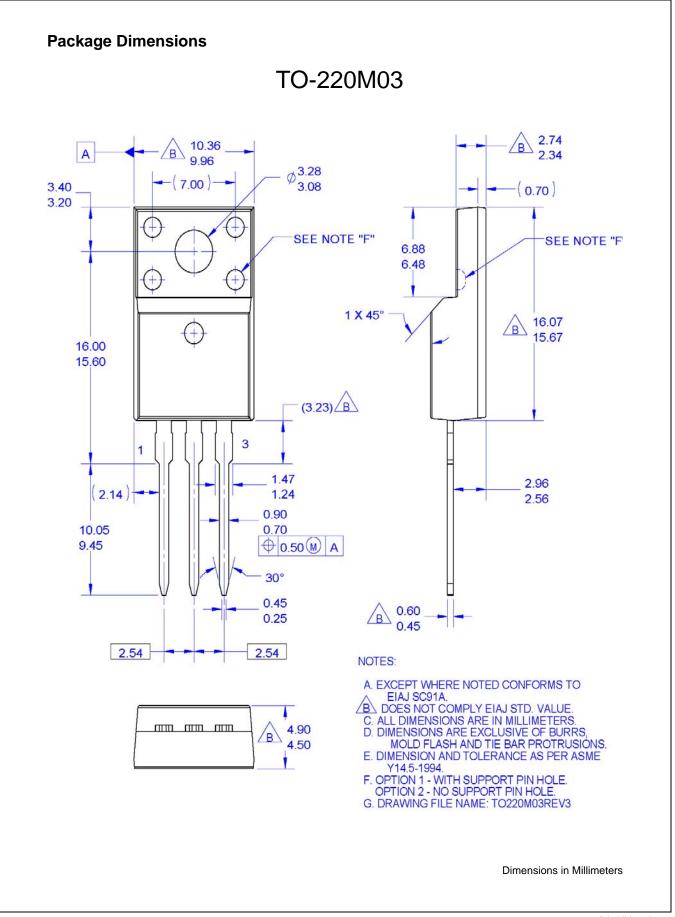






Peak Diode Recovery dv/dt Test Circuit & Waveforms







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